

PESDNC5D5VB ESD Protector

Description

The PESDNC5D5VB protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.

Feature

- 80W peak pulse power per line (t_P = 8/20µs)
- SOD-523 package
- Replacement for MLV(0603)
- Bidirectional configurations
- Protects one power or I/O port
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness:≤3mil

Electronics Parameter

Symbol	Parameter		
V _{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I $_{T}$		
Ι _Τ	Test Current		
IPP	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		
I _F	Forward Current		
VF	Forward Voltage @ I _F		

Applications

Cellular phones

Portable devices

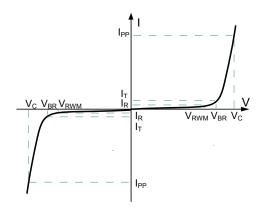
Digital cameras

Power supplies

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ESD Protector

PESDNC5D5VB

Electrical characteristics per line@25°C(unless otherwise specified)						
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}				5	V
Breakdown Voltage	V _{BR}	I _t = 1mA	6.0		8.0	V
Reverse Leakage Current	I _R	V _{RWM} = 5V T=25°C			1.0	μA
Junction Capacitance	Cj	V _R =0V f = 1MHz		20		pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20µs)	P _{pp}	80	W
Operating Temperature	TJ	-55 to +150	°C
Storage Temperature	T _{STG}	-55 to +150	°C

Typical Characteristics

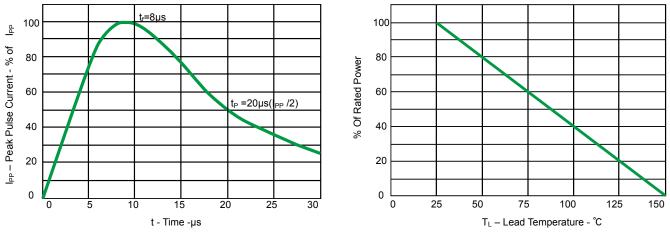
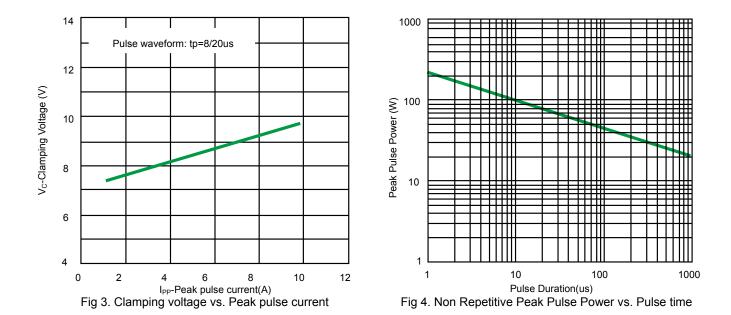


Fig 1.Pulse Waveform

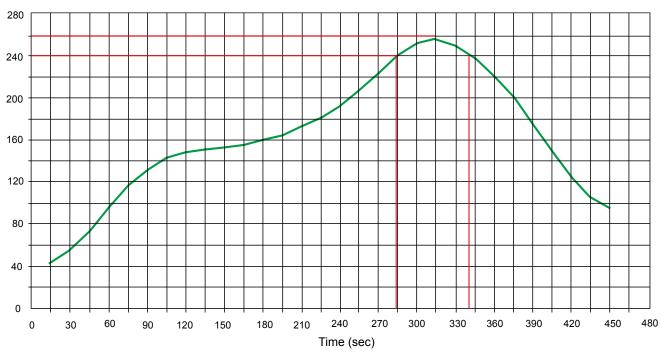
Fig 2. Power Derating Curve

ESD Protector

PESDNC5D5VB



Solder Reflow Recommendation



Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

PCB Design

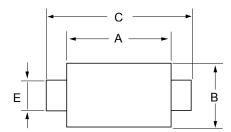
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

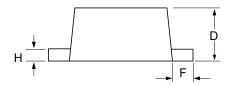
- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

ESD Protector

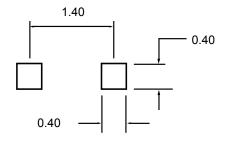
PESDNC5D5VB

Product dimension (SOD-523)





Dim	Inches		Millimeters		
Dim	MIN	MAX	MIN	МАХ	
А	0.043	0.051	1.10	1.30	
В	0.028	0.035	0.70	0.90	
С	0.059	0.067	1.50	1.70	
D	0.020	0.028	0.50	0.70	
E	0.010	0.014	0.25	0.35	
F	0.006	0.010	0.15	0.25	
Н	0.0028	0.0079	0.07	0.20	



Unit:mm

Ordering information

Device	Package	Shipping
PESDNC5D5VB	SOD-523 (Pb-Free)	3000 / Tape & Reel

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